

## T498C686K004ATE900

T498, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 68 uF, 10%, 4 VDC, SMD, MnO<sub>2</sub>, Molded, Hi-Temp, 150C, Auto, AEC-Q200, N/A, 900 mOhms, 6032, 2.8 mm, 1.3 mm



Click [here](#) for the 3D model.

### General Information

Series	T498
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, MnO <sub>2</sub> , Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	224.48 mg
Shelf Life	156 Weeks
MSL	1

### Dimensions

L	6mm +/-0.3mm
W	3.2mm +/-0.3mm
H	2.5mm +/-0.3mm
T	0.13mm REF
S	1.3mm +/-0.3mm
F	2.2mm +/-0.1mm
A	3.1mm MIN
B	0.5mm +/-0.15mm
E	2.4mm REF
G	2.8mm REF
P	0.9mm REF
R	1mm REF
X	0.1mm +/-0.1mm REF

### Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

### Specifications

Capacitance	68 uF
Tolerance	10%
Voltage DC	4 VDC (85C), 3.19 VDC (125C), 2.68 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5% 120Hz 25C
Failure Rate	N/A
ESR	900 mOhms (100kHz 25C)
Ripple Current	350 mA (rms, 100kHz 25C), 315 mA (rms, 85C), 105 mA (rms, 150C)
Leakage Current	2.7 uA (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.